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FGH30S150P 1500 V, 30 A Shorted-anode IGBT

Features

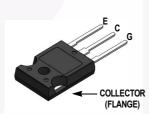
- · High Speed Switching
- Low Saturation Voltage: V_{CE(sat)} = 1.85 V @ I_C = 30 A
- High Input Impedance
- RoHS Compliant

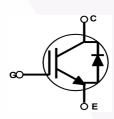
Applications

• Induction Heating, Microwave Oven



Using advanced field stop trench and shorted-anode technology, Fairchild's shorted-anode trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche capability. This device is designed for induction heating and microwave oven.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description	Ratings	Unit V		
V _{CES}	Collector to Emitter Voltage	1500			
V _{GES}	Gate to Emitter Voltage		±25	V	
I _C	Collector Current	@ T _C = 25°C	60	A	
	Collector Current	@ T _C = 100°C	30	A	
I _{CM (1)}	Pulsed Collector Current		90	A	
IF	Diode Continuous Forward Current	ontinuous Forward Current @ $T_{\rm C} = 25^{\circ}{\rm C}$ 60		A	
I _F	Diode Continuous Forward Current	ntinuous Forward Current @ $T_{\rm C} = 100^{\circ}{\rm C}$		A	
P _D	Maximum Power Dissipation	@ T _C = 25°C	500	W	
	Maximum Power Dissipation (a) $T_{\rm C} = 100^{\rm o}{\rm C}$		250	W	
Т _Ј	Operating Junction Temperature		-55 to +175	°C	
T _{stg}	Storage Temperature Range		-55 to +175	°C	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case, Max		0.3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max		40	°C/W

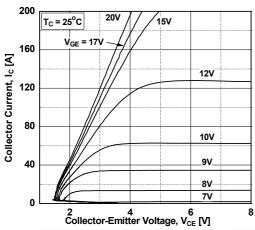
Notes: 1: Limited by Tjmax

March 2016

Package Marking and Orderir Device Marking Device FGH30S150P FGH30S150P		Device	Pac	Package Reel Size		Tape Width		Quantity	
		TO	TO-247 -			-		30	
Electric	al Chara	acteristics of	the IGE	3T T _C = 2€	5°C unless otherwise note	ť			
Symbol Parameter			Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristics								
BV _{CES}		Emitter Breakdown \	/oltage V	_{GE} = 0 V, I _C	- = 1 mA	1500	-	-	V
ΔBV_{CES} $\Delta T_{.1}$	Temperature Coefficient of Breakdown Voltage		kdown	$V_{GE} = 0 V, I_C = 1 mA$		_	1.5	-	V/ºC
I _{CES}	Collector Cut-Off Current		V	V _{CE} = 1500, V _{GE} = 0V		-	-	1	mA
I _{GES}	G-E Leakage Current			_{GE} = V _{GES} ,		-	-	±500	nA
On Charac				- 20~ 1	(-)/	4.5	6.0	75	14
V _{GE(th)}	G-E Thres	nold Voltage	-	; = 30mA, \ = 30A \/		4.5	6.0	7.5	V
				$I_{C} = 30A, V_{GE} = 15V$ $T_{C} = 25^{\circ}C$		-	1.85	2.4	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage		- 'C	$I_{\rm C}$ = 30A, $V_{\rm GE}$ = 15V, $T_{\rm C}$ = 125°C		-	2.06	-	v
			I _C T	_c = 30A, V _G _C = 175 ^o C	_E = 15V,	-	2.15	-	V
V _{FM}	V _{FM} Diode Forward Voltage		١ _F	$I_{\rm F}$ = 30A, $T_{\rm C}$ = 25°C		-	1.61	2.2	V
			١ _F	= 30A, T _C	= 175 ^o C	-	1.96	-	V
						1			
Dynamic C									
C _{ies}	Input Capa		v	_{CE} = 30V, V	/ _{GF} = 0V,	-	3310	-	pF
C _{oes}		put Capacitance		f = 1MHz		-	70	-	pF
C _{res}	Reverse II	ansfer Capacitance				-	55	-	pF
Switching	Characcteri	stics							
t _{d(on)}	Turn-On D	elay Time				-	32	-	ns
t _r	Rise Time					-	292	-	ns
t _{d(off)}	Turn-Off D	elay Time	v	_{CC} = 600V,	I _C = 30A,	-	492	-	ns
t _f	Fall Time		R	_G = 10Ω, V	′ _{GE} = 15V,	-	214	-	ns
Eon	Turn-On S	witching Loss	R	Resistive Load, T _C = 25°C		-	1.16	-	mJ
E _{off}	Turn-Off Sv	witching Loss				-	0.9	-	mJ
E _{ts}	Total Switc	hing Loss				-	2.06	-	mJ
t _{d(on)}	Turn-On D	elay Time				-	36		ns
t _r	Rise Time					-	336	- (ns
t _{d(off)}	Turn-Off D	elay Time	v	$V_{CC} = 600V$, $I_C = 30A$, $R_G = 10\Omega$, $V_{GE} = 15V$, Resistive Load, $T_C = 175^{\circ}C$		-	560		ns
t _f	Fall Time		R			-	520	-	ns
E _{on}	Turn-On S	witching Loss	R			-	1.39	-	mJ
E _{off}		witching Loss				-	1.86	-	mJ
E _{ts}	Total Switc	hing Loss				-	3.25	-	mJ
Qg	Total Gate	Charge				-	369	-	nC
-		-	V	V _{CE} = 600V, I _C = 30A,		_	23.5	-	nC
Q _{ge}	Gale to En	nitter Charge		_{GE} = 15V	0	_	20.0		



Figure 1. Typical Output Characteristics





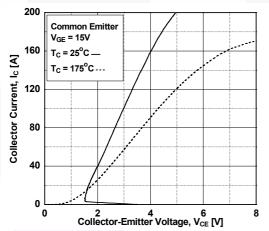


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

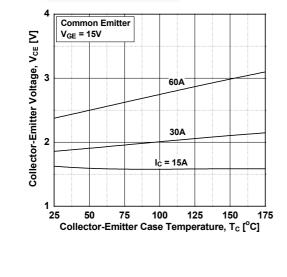


Figure 2. Typical Output Characteristics

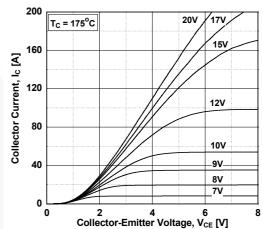


Figure 4. Transfer Characteristics

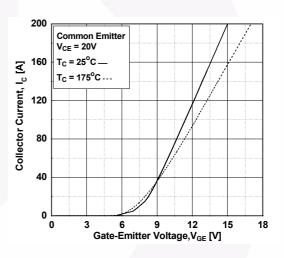
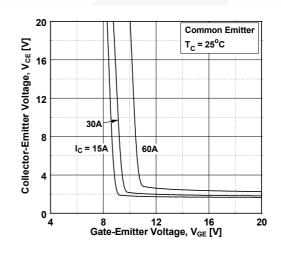
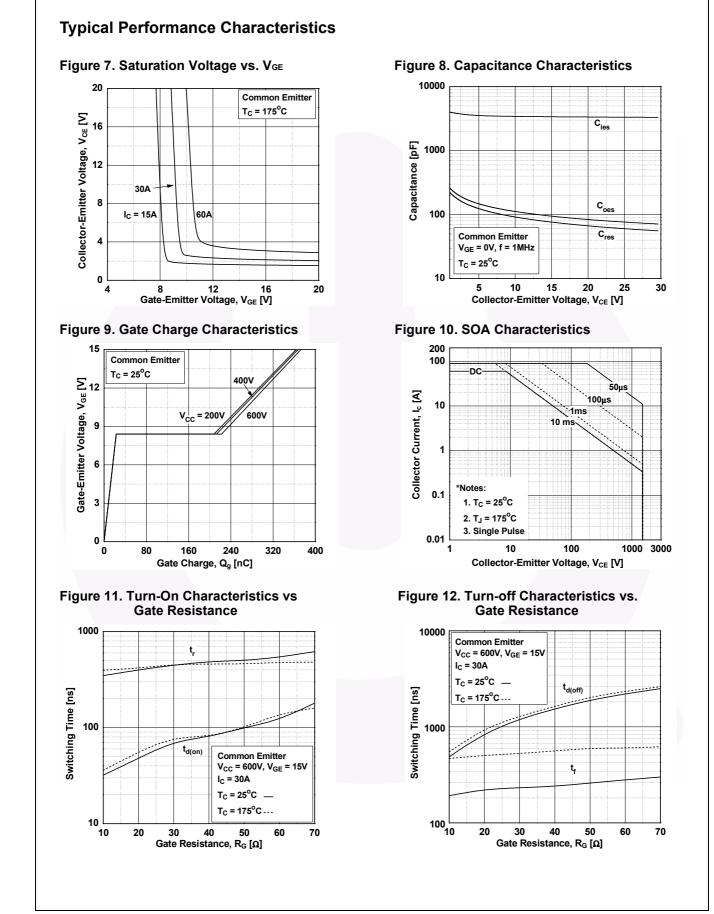


Figure 6. Saturation Voltage vs. VGE

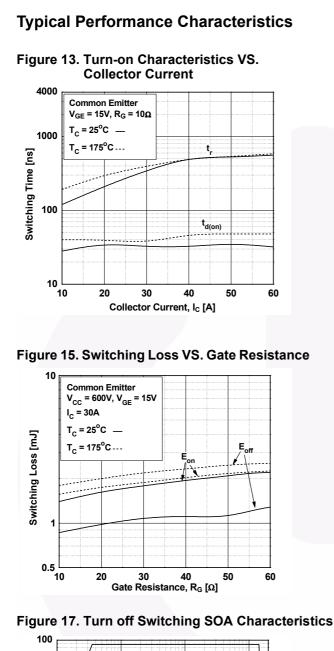


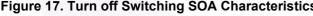
FGH30S150P — 1500 V, 30 A Shorted-anode IGBT



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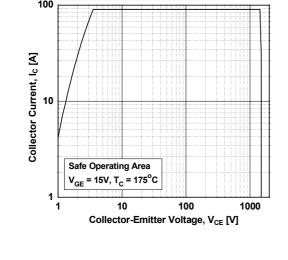


Figure 14.Turn-off Characteristics VS. **Collector Current**

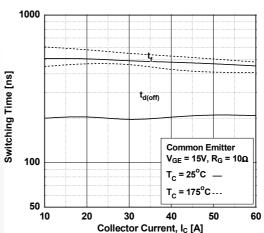
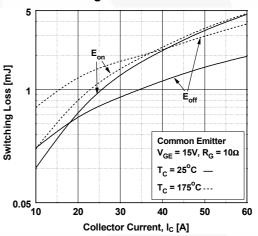
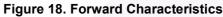
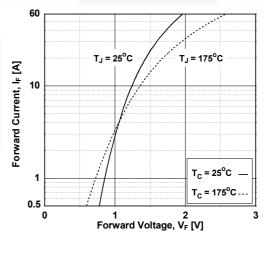
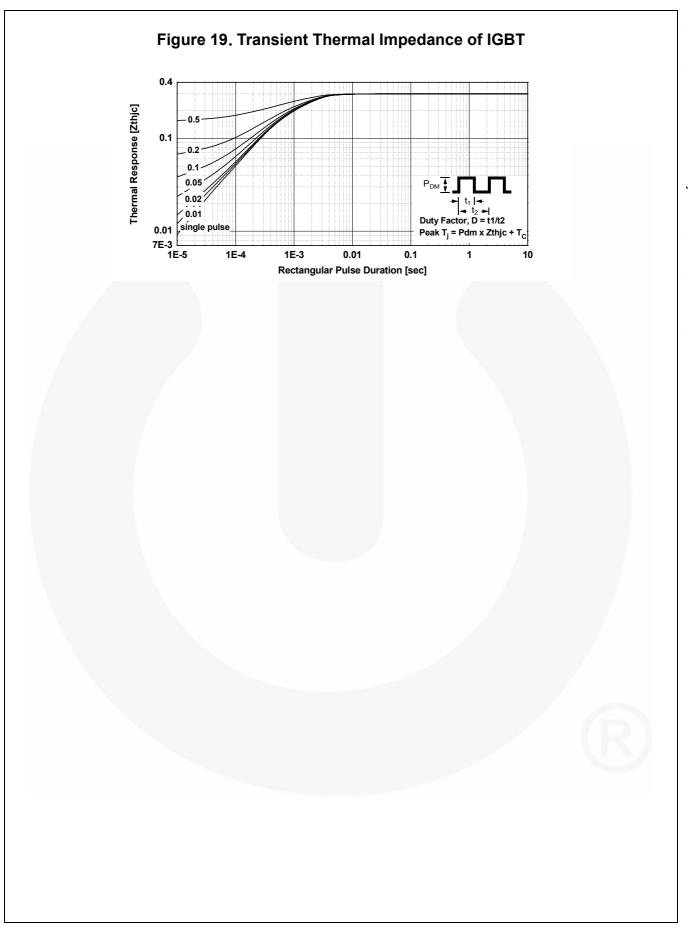


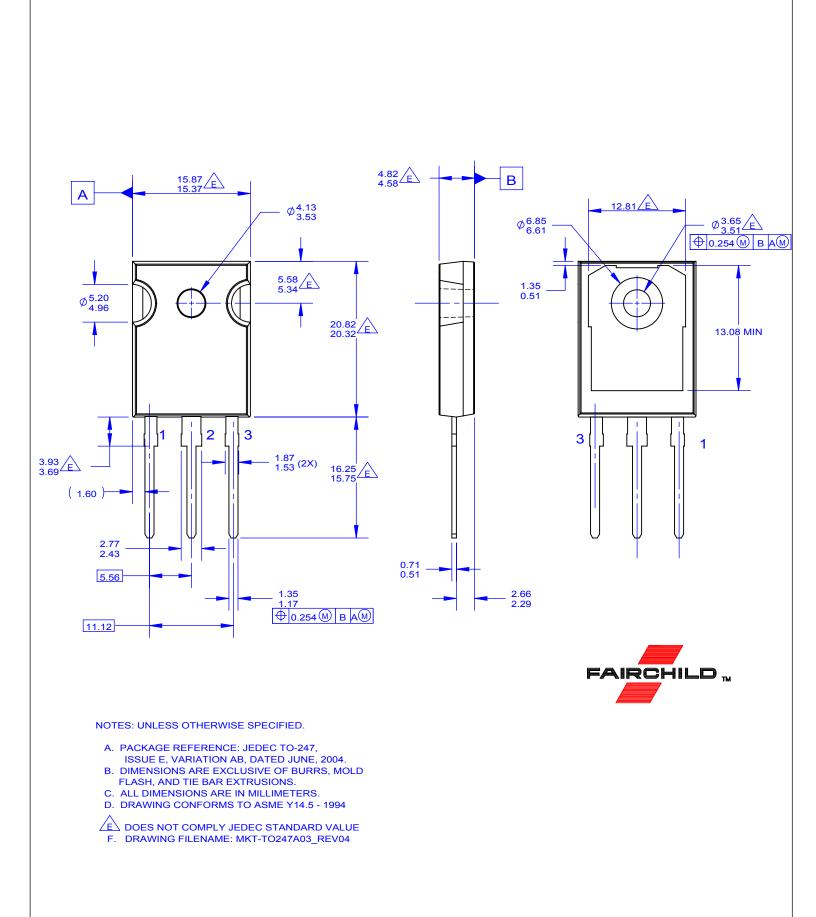
Figure 16. Switching Loss VS. Collector Current











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